

# Quantum Dot Solar Cells with Multiple Exciton Generation

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*Presented at the 2005 DOE Solar Energy Technologies  
Program Review Meeting  
November 7–10, 2005  
Denver, Colorado*

**Conference Paper**  
**NREL/CP-590-38992**  
**November 2005**

NREL is operated by Midwest Research Institute • Battelle Contract No. DE-AC36-99-GO10337



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## ABSTRACT

We have measured the quantum yield of the multiple exciton generation (MEG) process in quantum dots (QDs) of the lead-salt semiconductor family (PbSe, PbTe, and PbS) using fs pump-probe transient absorption measurements. Very high quantum yields (up to 300%) for charge carrier generation from MEG have been measured in all of the Pb-VI QDs. We have calculated the potential maximum performance of various MEG QD solar cells in the detailed balance limit. We examined a two-cell tandem PV device with singlet fission (SF), QD, and normal dye (N) absorbers in the nine possible series-connected combinations to compare the tandem combinations and identify the combinations with the highest theoretical efficiency. We also calculated the maximum efficiency of an idealized single-gap MEG QD solar cell with  $M$  multiplications and its performance under solar concentration.

### 1. Objectives

The objective of this continuing project is to explore the possibility of greatly enhanced conversion efficiency in third-generation PV cells based on charge multiplication in the process of multiple exciton generation (MEG) in low-bandgap semiconductor quantum dots (QDs).

### 2. Technical Approach

We use fs pump-probe transient absorption dynamics to study carrier relaxation and MEG processes in QDs. For efficiency calculations, we use a detailed-balance model in which we assume complete light absorption for photon energy greater than the absorption threshold, charge multiplication occurs by MEG or singlet fission (SF), all photogenerated carriers are collected, and the only loss mechanism is due to spontaneous radiative recombination.

### 3. Results and Accomplishments

Extending our previous measurements of high MEG quantum yield in PbSe QDs, we found similar MEG quantum efficiencies in PbS and PbTe QDs. The quantum yield reached 300% at  $4 \times E_g$ , where  $E_g$  is the bandgap of the QD.

We have generalized our model for calculating the maximum efficiency of an idealized MEG QD solar cell to include  $M$  multiplications and the expected performance under solar concentration. For a given bandgap,  $E_g$ , the maximum number of excitons,  $M_{\max}$ , that can be produced per photon by MEG is

dictated by energy conservation considerations. The value of  $M_{\max}$  is given by  $M_{\max} = E_{\max}/E_g$ , where  $E_{\max} \sim 4.4$  eV is the highest photon energy in the AM1.5 solar spectrum. As an example, for  $E_g = 0.75$  eV,  $M_{\max} = 5$ , as shown in Fig. 1.

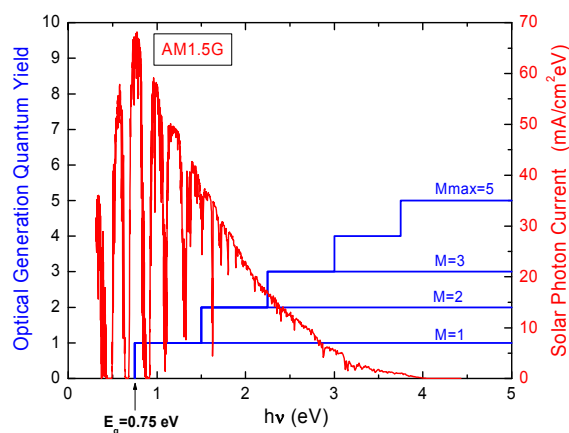


Fig. 1. MEG quantum yield models for  $E_g = 0.75$  eV overlapping the AM1.5G spectrum. The maximum possible multiplication for this bandgap is  $M_{\max} = 5$ .

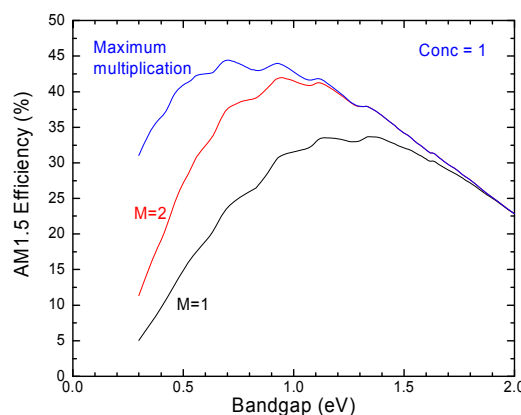


Fig. 2. Maximum efficiency at one sun for a MEG QD solar cell versus bandgap for multiplications of  $M = 1$ , 2, and  $M_{\max}$ .

The calculated efficiency versus bandgap for a MEG cell with  $M = 1$ , 2, and  $M_{\max}$  under one sun concentration is shown in Fig. 2. Allowing the maximum possible multiplication in a MEG cell raises the ultimate efficiency only a small amount compared to  $M = 2$  (from 42.0% at  $E_g = 0.95$  eV to 44.4% at  $E_g = 0.7$  eV). In general, cells with lower bandgap benefit more from allowing maximum multiplication. Figure 3

shows how the maximum efficiency of a MEG cell with maximum multiplication changes with concentration. The maximum possible efficiency at maximum multiplication is 84.9% at a bandgap of 0.05 eV.

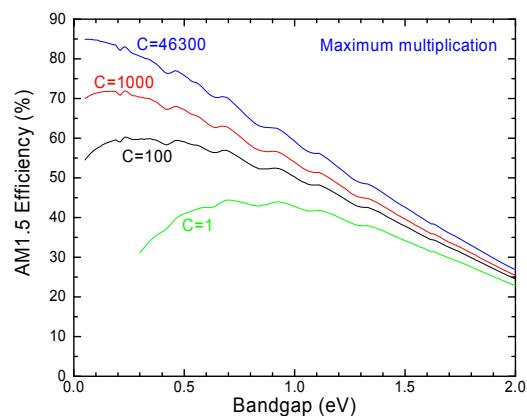


Fig. 3. Maximum efficiency versus bandgap of a MEG QD cell with maximum allowable exciton multiplication for different solar concentrations.

We have calculated the upper limits on the maximum efficiency of a two-gap tandem PV device with various combinations of a MEG QD absorber, a normal dye absorber (N), or an SF absorber as the top and bottom cells to identify the combinations with the highest theoretical efficiency. The efficiencies were calculated in the detailed-balance limit with the top and bottom cells electrically and optically in series.

The N-absorber generates one electron-hole (e-h) pair per photon absorbed above the bandgap. The QD-absorber generates two e-h pairs for photons with energy greater than twice the bandgap and one e-h pair for photons with energy between one and two times the bandgap. An ideal SF absorber has a triplet state ( $E_T = E_1$ ) and a singlet state ( $E_S = 2 \times E_1$ ). The SF-absorber absorbs all photons with energy above the singlet state at twice the triplet state energy ( $E_T = \text{bandgap}$ ) and generates two electrons per absorbed photon for photons in this energy range.

The maximum overall efficiency, along with the optimum bandgaps of the top and bottom cells for each of the nine possible combinations, is summarized in Table 1. The best absorber combinations, (SF,QD), (QD,N), (QD,QD), and (QD,SF), have a QD-absorber as the top cell or the bottom cell. These cells have a potential efficiency of greater than 47% for one sun illumination, which exceeds the value of 45.7% for the usual (N,N) tandem.

Table 1. Maximum AM1.5G theoretical efficiency for SF, QD, and N tandem cell combinations at the optimum top and bottom cell bandgaps.

Top/Bottom Absorber	Top Cell Bandgap (eV)	Bottom Cell Bandgap (eV)	Maximum Efficiency (%)
(N,N)	1.63	0.95	45.7
(N,QD)	1.61	0.95	45.7
(N,SF)	1.39	0.48	43.8
(QD,N)	1.63	0.95	47.1
(QD,QD)	1.46	0.68	47.6
(QD,SF)	1.40	0.48	47.3
(SF,N)	0.95	0.95	45.4
(SF,QD)	0.84	0.70	47.7
(SF,SF)	0.82	0.48	45.7

#### 4. Conclusions

We have measured very high MEG quantum yields (up to 300%) for charge carrier generation in Pb-VI QDs (VI = S, Se, Te). We have calculated the maximum attainable efficiencies of both single-gap and two-gap tandem cells that incorporate MEG QD absorbers. Future work will focus on studying the MEG process in other QD materials, producing information on charge transfer and optical properties of QD/TiO<sub>2</sub> composites, and modeling the electrical behavior and potential performance of MEG QD solar cells.

#### ACKNOWLEDGEMENTS

M.C. Hanna was supported by the NREL NCPV Solar Program. M.C. Beard, J.C. Johnson, R.J. Ellingson, J. Murphy, and A.J. Nozik were supported by the DOE Office of Science, Basic Energy Sciences, Division of Chemical Sciences. NREL work is performed under DOE contract DE-AC36-99-GO10337.

#### MAJOR FY 2005 PUBLICATIONS

R.J. Ellingson, M.C. Beard, J.C. Johnson, P. Yu, O.I. Micic, A.J. Nozik, A. Shabaev, and A.L. Efros, "Highly Efficient Multiple Exciton Generation in Colloidal PbSe and PbS Quantum Dots," *Nano Letters* **5**, 865 (2005).

# REPORT DOCUMENTATION PAGE

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<b>1. REPORT DATE (DD-MM-YYYY)</b> November 2005		<b>2. REPORT TYPE</b> Conference Paper		<b>3. DATES COVERED (From - To)</b>	
<b>4. TITLE AND SUBTITLE</b> Quantum Dot Solar Cells with Multiple Exciton Generation				<b>5a. CONTRACT NUMBER</b> DE-AC36-99-GO10337	
				<b>5b. GRANT NUMBER</b>	
				<b>5c. PROGRAM ELEMENT NUMBER</b>	
<b>6. AUTHOR(S)</b> M.C. Hanna, M.C. Beard, J.C. Johnson, J. Murphy, R.J. Ellingson, and A.J. Nozik				<b>5d. PROJECT NUMBER</b> NREL/CP-590-38992	
				<b>5e. TASK NUMBER</b> PVA6.0605	
				<b>5f. WORK UNIT NUMBER</b>	
<b>7. PERFORMING ORGANIZATION NAME(S) AND ADDRESS(ES)</b> National Renewable Energy Laboratory 1617 Cole Blvd. Golden, CO 80401-3393				<b>8. PERFORMING ORGANIZATION REPORT NUMBER</b> NREL/CP-590-38992	
<b>9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES)</b>				<b>10. SPONSOR/MONITOR'S ACRONYM(S)</b> NREL	
				<b>11. SPONSORING/MONITORING AGENCY REPORT NUMBER</b>	
<b>12. DISTRIBUTION AVAILABILITY STATEMENT</b> National Technical Information Service U.S. Department of Commerce 5285 Port Royal Road Springfield, VA 22161					
<b>13. SUPPLEMENTARY NOTES</b>					
<b>14. ABSTRACT (Maximum 200 Words)</b> We have measured the quantum yield of the multiple exciton generation (MEG) process in quantum dots (QDs) of the lead-salt semiconductor family (PbSe, PbTe, and PbS) using fs pump-probe transient absorption measurements. Very high quantum yields (up to 300%) for charge carrier generation from MEG have been measured in all of the Pb-VI QDs. We have calculated the potential maximum performance of various MEG QD solar cells in the detailed balance limit. We examined a two-cell tandem PV device with singlet fission (SF), QD, and normal dye (N) absorbers in the nine possible series-connected combinations to compare the tandem combinations and identify the combinations with the highest theoretical efficiency. We also calculated the maximum efficiency of an idealized single-gap MEG QD solar cell with M multiplications and its performance under solar concentration.					
<b>15. SUBJECT TERMS</b> Photovoltaics; solar; quantum dot solar cells; PV; NREL					
<b>16. SECURITY CLASSIFICATION OF:</b>			<b>17. LIMITATION OF ABSTRACT</b> UL	<b>18. NUMBER OF PAGES</b>	<b>19a. NAME OF RESPONSIBLE PERSON</b>
<b>a. REPORT</b> Unclassified	<b>b. ABSTRACT</b> Unclassified	<b>c. THIS PAGE</b> Unclassified			<b>19b. TELEPHONE NUMBER (Include area code)</b>